Kibog Park

List of Publications by Year in descending order

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52	1,196	18	34
papers	citations	h-index	g-index
54	54	54	2319
all docs	docs citations	times ranked	citing authors

#	Article	IF	CITATIONS
1	Near room-temperature synthesis of transfer-free graphene films. Nature Communications, 2012, 3, 645.	12.8	205
2	Growth and characterization of \hat{l}^2 -Ga2O3 thin films by molecular beam epitaxy for deep-UV photodetectors. Journal of Applied Physics, 2017, 122, .	2.5	124
3	Negative Poisson's ratios in metal nanoplates. Nature Communications, 2014, 5, 3255.	12.8	112
4	Research on flexible display at Ulsan National Institute of Science and Technology. Npj Flexible Electronics, 2017, $1, \dots$	10.7	59
5	Growth and Simultaneous Valleys Manipulation of Two-Dimensional MoSe ₂ -WSe ₂ Lateral Heterostructure. ACS Nano, 2017, 11, 8822-8829.	14.6	54
6	Growth of Wrinkle-Free Graphene on Texture-Controlled Platinum Films and Thermal-Assisted Transfer of Large-Scale Patterned Graphene. ACS Nano, 2015, 9, 679-686.	14.6	52
7	High-Performance Plasmonic THz Detector Based on Asymmetric FET With Vertically Integrated Antenna in CMOS Technology. IEEE Transactions on Electron Devices, 2016, 63, 1742-1748.	3.0	41
8	Stretchable Dual-Capacitor Multi-Sensor for Touch-Curvature-Pressure-Strain Sensing. Scientific Reports, 2017, 7, 10854.	3.3	37
9	On-Display Transparent Half-Diamond Pattern Capacitive Fingerprint Sensor Compatible With AMOLED Display. IEEE Sensors Journal, 2016, 16, 8124-8131.	4.7	35
10	One-step graphene coating of heteroepitaxial GaN films. Nanotechnology, 2012, 23, 435603.	2.6	33
11	Monolithic graphene oxide sheets with controllable composition. Nature Communications, 2014, 5, 3383.	12.8	31
12	Quantum well state of self-forming3Câ^'SiCinclusions in4HSiC determined by ballistic electron emission microscopy. Physical Review B, 2004, 69, .	3.2	30
13	One-Dimensional Assembly on Two-Dimensions: AuCN Nanowire Epitaxy on Graphene for Hybrid Phototransistors. Nano Letters, 2018, 18, 6214-6221.	9.1	30
14	Facile Synthesis of Few-Layer Graphene with a Controllable Thickness Using Rapid Thermal Annealing. ACS Applied Materials & Samp; Interfaces, 2012, 4, 1777-1782.	8.0	28
15	Strong Fermi-Level Pinning at Metal/n-Si(001) Interface Ensured by Forming an Intact Schottky Contact with a Graphene Insertion Layer. Nano Letters, 2017, 17, 44-49.	9.1	26
16	Performance Enhancement of Plasmonic Sub-Terahertz Detector Based on Antenna Integrated Low-Impedance Silicon MOSFET. IEEE Electron Device Letters, 2015, 36, 220-222.	3.9	23
17	In situ observations of gas phase dynamics during graphene growth using solid-state carbon sources. Physical Chemistry Chemical Physics, 2013, 15, 10446.	2.8	21
18	Ferroelectric enhancement of La-doped BaTiO3 thin films using SrTiO3 buffer layer. Thin Solid Films, 2014, 551, 127-130.	1.8	19

#	Article	IF	CITATIONS
19	Logarithmic temperature variations of the elastic constant of barium titanate near the ferroelectric phase transition. Current Applied Physics, 2012, 12, 1185-1189.	2.4	18
20	Schottky barrier modulation of metal/4H-SiC junction with thin interface spacer driven by surface polarization charge on 4H-SiC substrate. Applied Physics Letters, 2015, 107, .	3.3	17
21	Effect of inclined quantum wells on macroscopic capacitance-voltage response of Schottky contacts: Cubic inclusions in hexagonal SiC. Applied Physics Letters, 2005, 86, 222109.	3.3	15
22	Quantum well behavior of single stacking fault 3C inclusions in 4H-SiC p-i-n diodes studied by ballistic electron emission microscopy. Applied Physics Letters, 2005, 87, 232103.	3.3	15
23	Photoresponse enhancement of plasmonic terahertz wave detector based on asymmetric silicon MOSFETs with antenna integration. Japanese Journal of Applied Physics, 2014, 53, 04EJ05.	1.5	14
24	Precursor polar clusters in the paraelectric phase of ferroelectric Ba _{0.80} Ca _{0.20} TiO ₃ single crystals studied by Brillouin light scattering. Journal of Physics Condensed Matter, 2010, 22, 225904.	1.8	12
25	Reduction of water-molecule-induced current-voltage hysteresis in graphene field effect transistor with semi-dry transfer using flexible supporter. Journal of Applied Physics, 2019, 125, .	2.5	12
26	Low-temperature formation of epitaxial graphene on 6H-SiC induced by continuous electron beam irradiation. Applied Physics Letters, 2012, 101, 092105.	3.3	11
27	Negative Fermi-Level Pinning Effect of Metal/n-GaAs(001) Junction Induced by a Graphene Interlayer. ACS Applied Materials & Samp; Interfaces, 2019, 11, 47182-47189.	8.0	11
28	Highly Flexible Touch Screen Panel Fabricated with Silver Nanowire Crossing Electrodes and Transparent Bridges. Journal of the Optical Society of Korea, 2015, 19, 508-513.	0.6	11
29	Valence band structure and band offset of 3C- and 4H-SiC studied by ballistic hole emission microscopy. Applied Physics Letters, 2006, 89, 042103.	3.3	10
30	Design and Characterization of Plasmonic Terahertz Wave Detectors Based on Silicon Field-Effect Transistors. Japanese Journal of Applied Physics, 2012, 51, 06FE17.	1.5	9
31	Simulations of denuded-zone formation during growth on surfaces with anisotropic diffusion. Physical Review B, 2003, 68, .	3.2	8
32	Enhanced Crystallinity of Epitaxial Graphene Grown on Hexagonal SiC Surface with Molybdenum Plate Capping. Scientific Reports, 2015, 5, 9615.	3.3	7
33	Highly-Sensitive Thin Film THz Detector Based on Edge Metal-Semiconductor-Metal Junction. Scientific Reports, 2017, 7, 16830.	3.3	7
34	Low-Cost and Fast-Response Resistive Humidity Sensor Comprising Biopolymer-Derived Carbon Thin Film and Carbon Microelectrodes. Journal of the Electrochemical Society, 2020, 167, 147511.	2.9	7
35	Giant Electroresistance in Edge Metal-Insulator-Metal Tunnel Junctions Induced by Ferroelectric Fringe Fields. Scientific Reports, 2016, 6, 30646.	3.3	6
36	Capacitive Heart-Rate Sensing on Touch Screen Panel with Laterally Interspaced Electrodes. Sensors, 2020, 20, 3986.	3.8	5

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#	Article	IF	Citations
37	C ₆₀ Adsorbed on TiO ₂ Drives Dark Generation of Hydroxyl Radicals. ACS Catalysis, 2022, 12, 5990-5996.	11.2	5
38	Nanometer-resolution measurement and modeling of lateral variations of the effective work function at the bilayer <mml:math display="inline" xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:mrow><mml:mtext>Pt</mml:mtext><mml:mo>/</mml:mo><mml:mtext>Al</mml:mtext>Physical Review B, 2009, 80, .</mml:mrow></mml:math>	t> <mmth:ma< td=""><td>o>/</td></mmth:ma<>	o>/
39	Ferroelectric phase transitions studied by dielectric and light scattering spectroscopies on Ba1â^'Ca TiO3 single crystals (x= 0.12, 0.20). Ceramics International, 2012, 38, S21-S24.	4.8	4
40	Unveiling the Direct Correlation between the CVD-Grown Graphene and the Growth Template. Journal of Nanomaterials, 2018, 2018, 1-6.	2.7	4
41	Self-selective ferroelectric memory realized with semimetalic graphene channel. Npj 2D Materials and Applications, 2021, 5, .	7.9	4
42	Dependence of spontaneous polarization on stacking sequence in SiC revealed by local Schottky barrier height variations over a partially formed 8H-SiC layer on a 4H-SiC substrate. Applied Physics Letters, 2011, 99, .	3.3	3
43	TCAD modeling and simulation of non-resonant plasmonic THz detector based on asymmetric silicon MOSFETs., 2013,,.		3
44	Controllable Synthesis of Grapheneâ€Encapsulated Lowâ€Dimensional Nanocomposites. Advanced Materials Interfaces, 2015, 2, 1500112.	3.7	3
45	Cubic inclusions in 4H-SiC studied with ballistic electron-emission microscopy. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2004, 22, 1351-1355.	2.1	2
46	Formation of graphene on amorphous SiC film by surface-confined heating with electron beam irradiation. Current Applied Physics, 2018, 18, 335-339.	2.4	2
47	Effect of Ca Content on the Acoustic Anomalies of Ba1-xCaxTiO3 Single Crystals Studied by Brillouin Light Scattering. Journal of the Korean Physical Society, 2011, 59, 2575-2578.	0.7	2
48	Terahertz antenna compatible with CMOS array detector for a real-time T-ray imaging system. , 2012, , .		1
49	Surface-induced transition of nematic liquid crystals on graphene/SiC substrate. Europhysics Letters, 2018, 124, 46004.	2.0	1
50	Multi-Level Capacitive Memory Effect in Metal/Oxide/Floating-Schottky Junction. Journal of the Korean Physical Society, 2019, 74, 979-983.	0.7	1
51	Optical and microstructural properties of InGaN/GaN multiple quantum wells with embedded graphene coating. Journal of Alloys and Compounds, 2017, 713, 87-94.	5 . 5	0
52	Edge-over MOSFET with poly-Si thin film channel for achieving thermodynamic limit of subthreshold swing in nanometer scale. Semiconductor Science and Technology, 2019, 34, 095014.	2.0	0